GD3162_SDS

具有动态栅极驱动调节功能的先进的IGBT/SiC栅极驱动器

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产品简介



1 简介

GD3162是一款先进的电隔离单通道栅极驱动器,可驱动针对xEV牵引逆变器的最新SiC和IGBT模块。该器件通过提高栅极驱动功能,节省了空间并提升了性能。

GD3162提供集成的电隔离功能,可以通过SPI接口进行编程,具有先进的可编程保护功能,如过温、退饱和以及电流感测保护。GD3162集成了增强功能,可直接驱动大多数SiC MOSFET和IGBT/SiC模块栅极,并能够调节栅极驱动能力,以提高功率器件的开关性能并降低电压应力。

栅极强度的控制可以通过SPI命令或GS使能引脚来实现。GS_ENH逻辑控制开启时的驱动强度,GS_ENL控制关闭时的驱动强度。为了进一步提高性能,这些功能设计为彼此独立运行。通过输入引脚上的三电平功能或SPI命令,提供了三个独立的上拉驱动强度和三个下拉驱动强度。

GD3162可自主管理故障,并通过INTB引脚报告功率器件和栅极驱动的状态。VCE/VDS监测以及VGE监测可选择在INTA/RTRPT引脚上输出。

GD3162具有自检和控制保护功能,适用于功能安全级别较高的系统(ASIL C/D)的设计,满足汽车应用的严苛要求,完全符合AEC-Q1001级标准。



2 特性和优势

本节总结了GD3162的主要特性、安全特性和监管认证。

2.1 主要特性

- 集成电信号隔离 (高达8kV)
- 可提高驱动强度: 通过选择栅极驱动强度, 可提供高达10A/20A/30A的拉电流/灌电流
- SPI或三态GS_ENH和GS_ENL低压域引脚可以动态控制栅极驱动强度。支持高达20 KHz的栅极强度调节
- 双栅极上拉引脚和双栅极下拉引脚可增强驱动能力、同步调整栅极驱动强度、降低弱驱动时的热负载,并对每个驱动状态操作进行独立验证。
- SPI可编程ISEN/COMP设置点,允许栅极驱动器根据高压域输入自动控制栅极驱动强度。
- 温度感测引脚可兼容NTC和PTC热敏电阻,可实现基于温度的栅极驱动强度本地控制,支持通过AOUT引脚或SPI进行功率器件温度监测。
- 可编程ADC延迟——从PWM上升沿或下降沿开始,最大采样延迟为8µs。
- 主动总线放电功能(仅限MGD3162AM551EK和MGD3162AM581EK) 提供MCU控制或安全逻辑控制的栅极驱动,对母线电容进行主动放电。
- 用于RDSon和结温估算的VDS测量功能
- 提供SPI接口,可用于安全监测、配置和诊断报告
- 通过低压域INTA/RTRPT引脚监控VCE功率器件
- 支持高PWM开关频率: PWM频率高达100kHz, 由于散热限制
- 低压和高压域的故障安全状态管理,进入用户可选择的安全状态
- 对可配置的退饱和与电流感测进行了优化,可保护SiC和IGBT的反应时间少于lus
- INTA/RTRPT和INTB中断引脚,适用于电流和电压故障报告以及还可以配置为VCE或VGE状态的实时报告。
- 先进两级关断(2LTO)与软关断栅极电流相结合,可降低与快速关断相关的电流和电压应力。
- CMTI > 100V/ns

2.2 安全特性

- 认证符合ISO 26262, 支持ASIL D级功能安全
- 使用8位CRC对SPI和配置数据进行错误检查
- 通过可配置的INTB和/或INTA/RTRPT引脚以及SPI接口自主管理严重故障并报告状态
- VCE/VGE逐周期实时监测和报告,以反馈功率器件的状态
- 所有模拟和数字电路的自检 (BIST)
- 透过隔离屏障持续监测通信
- 死区时间强制执行
- 低压电路5V偏置供电的过压和欠压监控
- 高压电路VCC供电的过压和欠压监控
- 低压侧和高压侧都有专用的故障安全状态管理引脚

GD3162_SDS

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2.3 安全和监管认证

- 按照DIN V VDE V 0884-10标准加强了隔离
- 根据UL 1577标准,可承受5000V rms (1分钟)隔离电压
- 符合AEC-Q100 1级汽车标准

3 订购信息

表1. 可订购的部件型号

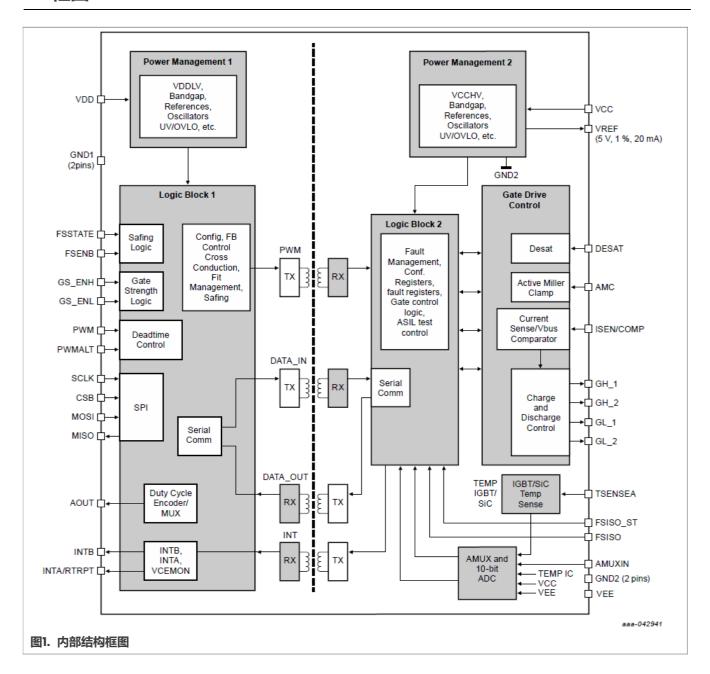
部件型号[1]	VDD (V)	外部电气间隙和爬电距离(mm)	材料(隔离) 组	温度(T」) (°C)	封装
MGD3162AM550EK (无直流母 线放电模式)	5.0	>7.72 ^[2]	II[3]	-40至150	32引脚宽体 SOIC, 0.65mm间距
MGD3162AM551EK (带直流母 线放电模式)	5.0	>7.72 ^[2]	II[3]	-40至150	32引脚宽体 SOIC, 0.65mm间距
MGD3162AM580EK (无直流母 线放电模式)	5.0	>8.00 ^[2]	I [3]	-40至150	32引脚宽体 SOIC, 0.65mm间距
MGD3162AM581EK (带直流母 线放电模式)	5.0	>8.00 ^[2]	_[[3]	-40至150	32引脚宽体 SOIC, 0.65mm间距

^[1] 若要订购卷带包装的器件,请在器件编号后添加后缀R2。如需订购托盘包装的器件,请在器件编号后添加后缀T。

^[2] 根据IEC 60950-1表2K和2N

^[3] 根据IEC 60664-1标准

4 框图



5 极限值

表2. 最大额定值

所有电压都以GND1(低压域)或GND2(高压域)为参考。除非另有说明,T.=-40至150℃。指定引脚的输入电流为正,输出电流为负。

符号	说明 (额定值)	最小值	最大值	单位
电源和电流参考值				·
V _{VDD}	低压域逻辑供电电压,5.0 V [1]	-0.3	6.0	V
V _{VCC}	高压域正供电电压 [2]	-0.3	25	V
V _{VEE}	高压域负电源电压 [2]	-12	0.3	V
V _{VCC-VEE}	高压域正/负供电电压	-0.3	35	V
V _{VREF}	VREF电压 [2]	-0.3	6.0	V
I _{VREF}	VREF输出电流	-	-20	mA
逻辑引脚				
V _{IN}	逻辑输入引脚电压 (FSSTATE、FSENB、PWM、PWMALT、GS_ENH、GS_ENL、SCLK、CSB [1] 和MOSI)	-0.3	18	V
V _{OUT}	逻辑输出引脚电压 (MISO、INTB、INTA/RTRPT、AOUT)	-0.3	V _{VDD} + 0.3	y v
V _{FSISO}	逻辑输入引脚电压 (FSISO)	-0.3	12	V
V _{FSISO_ST}	逻辑输入引脚电压 (FSISO_ST)	-0.3	12	V
栅极驱动输出级				
V _{GH_1,2}	GH_1,2电压	V _{VEE} - 0	.3 V _{vcc} + 0.3	3 V
V _{GL_1,2}	GL_1,2电压 [2]	V _{VEE} - 0	.3 V _{vcc} + 0.3	3 V
V _{AMC}	AMC电压	V _{VEE} - 0	.3 V _{vcc} + 0.3	3 V
温度感测引脚				
V _{TSENSEA}	TSENSEA电压 [2]	-0.3	6.0	V
中断引脚			<u> </u>	<u>.</u>
I _{INTA/RTRPT}	开漏直流输出电流	_	-20	mA
I _{INTB}	开漏直流输出电流	-	-20	mA
ISENSE感测引脚			<u> </u>	<u>.</u>
VISEN/COMP	ISEN/COMP电压	-2.0	V _{vcc} + 0.3	3 V V
AMUXIN引脚			·	
V _{AMUXIN}	AMUXIN电压 [2]		6.0	V
ESD额定值		· I		
V _{ESDHBM}	ESD电压 (HBM)			kV
	所有引脚	-2.0	2.0	
V _{ESDCDM}	ESD电压 (CDM)			V
	角引脚	-750 -500	750 500	
V	其他引脚 [7]		500	1,,,
V _{ESDModule}	ESD电压(模块级) GND1、GND2引脚	-8.0	8.0	kV
抗扰度	OMPT OMPT OF THE OWN OF THE OWN OF THE OWN OF THE OWN	1 0.0	10.0	
dV _{iso} /dt	共模瞬变抗扰度 [8]	I_	100	V/ns
		<u> </u>	1.00	1 - /

- [1] Ref = GND1
- [2] Ref = GND2
- [3] V_{INTB}, V_{INTA/RTRPT} < 1.0 V
- [4] ADC在AMUXIN引脚注入了高达500µA的电流时仍能正常工作并保持其性能。
- [5] 器件级人体模型 (HBM)

ANSI/ESDA/JEDEC JS-001: 2010模型HBM (人体模型)

静电放电 (ESD) 灵敏度测试人体模型 (HBM)

测试点:引脚至GNDI和引脚至GND2

[6] 器件带电模型 (CDM)

ANSI/ESD S5.3.1-2009

ESD协会静电放电灵敏度测试标准 - 器件带电模型 (CDM) - 元器件级

[7] 模块级ESD测试

ISO 10605:2008/Cor. 1:2010(E)

道路车辆——静电放电电器干扰测试方法

[8] 脉宽 = 10 ns

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6 修订历史

表3. 修订历史

文档ID	发布日期	数据手册状态	变更通知	替换版本	
GD3162_SDS	2024年1月12日	产品	_	v.l.l	
v.2.0					
更改	更新了文件标题 状态由 "目标" 改为 "产品"				
	• 第2.1节: 将第/	\项从" (仅PGD3162 AM551EK和PGD3162AM581EK) " 改为)" (仅MGD3162AN	//551EK和	
MGD3162AM581EK) "					
		牛编号从"PGD3162AM550EK"、"PGD3162AM551EK"、		***	
		58IEK" 改为 "MGD3I62AM550EK"、 "MGD3I62AM55IEk	(" 、 "MGD3162AN	//580 EK"和	
	"MGD3162AM581EK"				
	<u> 修订历史</u> 已更新,符合恩智浦的文档内容层级结构。				
GD3162_SDS	2023年5月10日	目标	_	v.1.0	
v.l.l					
更改	• 修正了封面上的状态。				
	 第2.1节:增加了一项 "用于RDSon和结温估算的VDS测量功能"。 第3节:在第一个脚注中增加了 "如需订购托盘包装的零部件,请在零件编号后添加后缀T"。 第5节 将标题 "绝对最大额定值" 更新为 "极限值"。 				
	- 表2: 删除了"栅极驱动输出状态"小标题下的最后四行。				
GD3162_SDS	2022年11月29日	目标	_	-	
v.1.0					
更改	-				

Legal information

Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- 2] The term 'short data sheet' is explained in section "Definitions".
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GD3162_SDS

具有动态栅极驱动调节功能的先进的IGBT/SiC栅极驱动器

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